

5440, DM7440

Dual 4-Input NAND Buffer

This device contains two, 4 input gates that perform the Logic NAND function. Outputs have 48 mA I_{OL}.

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

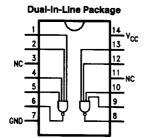


5440/DM7440 Dual 4-Input NAND Buffer

General Description

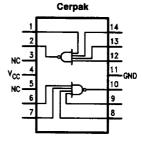
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Connection Diagrams



TL/F/9777-1

Order Number 5440DMQB, DM5440J or DM7440N See NS Package Number J14A or N14A



TL/F/9777-2

Order Number 5440FMQB See NS Package Number W14B

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage Input Voltage 5.5V Operating Free Air Temperature Range

54 -55°C to +125°C **DM74** 0°C to +70°C Storage Temperature Range -65°C to +150°C Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	5440			DM7440			Units
		Min	Nom	Max	Min	Nom	Max	Units
V _{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	٧
VIH	High Level Input Voltage	2			2			v
V _{IL}	Low Level Input Voltage			0.8		·	0.8	v
ЮН	High Level Output Current			-1.2			-0.4	mA
loL	Low Level Output Current			48			48	mA
TA	Free Air Operating Temperature	-55		125	0		70	°C

Electrical Characteristics

Over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
Vı	Input Clamp Voltage	$V_{CC} = Min, I_1 = -12 \text{ mA}$				-1.5	٧
V _{OH}	High Level Output Voltage	$V_{CC} = Min, I_{OH} = Max$ $V_{IL} = Max$		2.4	3.4		V
V _{OL}	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min$			0.2	0.4	٧
l _l	Input Current @ Max Input Voltage	V _{CC} = Max, V _I = 5.5V				1	mA
I _{IH}	High Level Input Current	V _{CC} = Max, V _I = 2.4V				40	μΑ
I _{IL}	Low Level Input Current	V _{CC} = Max, V _I = 0.4V				1.6	mA
los	Short Circuit Output Current	V _{CC} = Max (Note 2)	54	-20		-70	mA
			DM74	-18		-70	
Іссн	Supply Current with Outputs High	V _{CC} = Max				8	mA
CCL	Supply Current with Outputs Low	V _{CC} = Max				27	mA

Note 1: All typicals are at $V_{CC} = 5V$, $T_A = 25$ °C.

Note 2: Not more than one output should be shorted at a time.

Switching Characteristics at $V_{CC} = 5V$ and $T_A = 25^{\circ}C$ (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter	Conditions	Min	Max	Units
t _{PLH}	Propagation Delay Time Low to High Level Output	$C_L = 15 pF$ $R_L = 400 \Omega$		22	ns
^t PHL	Propagation Delay Time High to Low Level Output			15	ns